NSN 5961-01-461-3755

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-461-3755 **Inclosure Material:** Plastic **Overall Length:** 9.5 millimeters **Overall Diameter:** 5.2 millimeters **End Application:** 6030-01-414-8582 Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-201ad **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 3.00 amperes forward current, average absolute and 200.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No